

## LDMOS Power Linear Amplifier, Ultra Broadband 20-100MHz, 52dB Gain, SMA Female Connectors, 80 Watts

### RAMP-20-1000M-52d-Sf-80W-e7



This amplifier utilizes silicon LDMOS power devices that provide high gain, wide dynamic range, low distortion and good linearity.

- Solid-state Class AB linear design
- Extremely wide instantaneous bandwidth
- Compact and lightweight
- M&C Monitor and Control
- Suitable for all modulation schemes, ATSC, DVB-T, MediaFLO
- 50 ohm input and output impedance
- Highly rugged and reliable

#### ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Min	Typ	Max	Unit
Operating Frequency	BW	20		1000	MHz
Power Output (CW)	P <sub>SAT</sub>	80			Watt
Output Power @ 1 dB Gain Compression Point	P <sub>1dB</sub>	50			Watt
Output Power @ DVB-T Modulation	P <sub>MOD</sub>		20		Watt
Peak to Average Ratio	PAR		8.3		dB
Small Signal Gain	G <sub>1dB</sub>	49	52	55	dB
Input Power for Rated P <sub>out</sub>	P <sub>IN</sub>		0		dBm
Small Signal Gain Flatness	ΔG			±1.5	dB
Gain Adjustment Range	VVA	25	30		dB
Input Return Loss	S <sub>11</sub>			-10	dB
Noise Figure @ Max Gain	NF			10	dB
Third Order Intercept Point 2-Tones @ 43 dBm/Tone, Δ = 0.1 – 30MHz	IP3		+53		dBm
Harmonics @ rated P <sub>1dB</sub>	2 <sup>nd</sup> / 3 <sup>rd</sup>		-40 / -20		dBc
Spurious Signals	Spur			-60	dBc
Operating Voltage	VDC	26	28	30	Volt
Supply Current @ 80 Watts RF Output	I <sub>DD</sub>			9.0	Amp
Quiescent Current	I <sub>DQ</sub>		6.2		Amp
Switching Speed (10% to 90%)	T <sub>SW</sub>		2	5	μs

#### ENVIRONMENTAL CHARACTERISTICS

Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	T <sub>c</sub>	-40		+85	°C
Storage Temperature	T <sub>stg</sub>	-40		+85	°C
Relative Humidity (non-condensing)	RH	95			%
Altitude	ALT		40,000		Feet
Shock and Vibration	SH / VI		MIL-STD-810F		

#### MECHANICAL SPECIFICATIONS

Parameter	Value	Units	Limits
Dimensions	6.4 x 3.4 x 1.1	Inch	Max
Weight	1.0	lb.	Max
RF Connectors, Input/Output	SMA female		
DC Connectors	D-Sub, 9-Pins		
Cooling	External Heatsink		

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#### PROTECTIONS

Input Overdrive	+10 dBm	Max
Load VSWR @ Pout = 80W	$\infty:1$ @ all load phase and amplitude	Nom
Thermal Overload	Graceful degradation	Max

#### INTERFACE CONNECTOR – D-Sub, 9-Pin

Pin #	Description	Specifications
1	Reserved	N/C
2	Current Consumption Monitor	Analog voltage relative to ID @ 50 mV/100 mA
3	Temperature Monitor	Analog voltage relative to module's temperature @ 10 mV/°C
4	VVA	N/A
5	Shutdown	Amplifier Enable: TTL "Low" (Logic 0) Amplifier Disable: TTL "High" (Logic 1)
6, 7	VDD	+28 VDC $\pm$ 2 VDC
8, 9	GND	Ground

#### Adequate Heat Sink Required OUTLINE DRAWING

